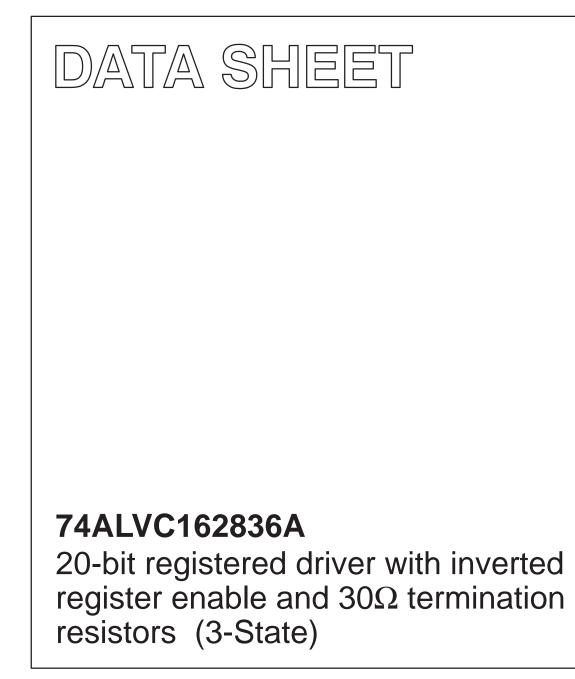
INTEGRATED CIRCUITS



Product specification Replaces datasheet 74ALVC162836 of 2000 Jan 03 IC24 Data Handbook 2000 Mar 14



74ALVC162836A

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- Complies with JEDEC standard no. 8-1A.
- CMOS low power consumption
- Direct interface with TTL levels
- Current drive ± 12 mA at 3.0 V
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- Output drive capability 50 Ω transmission lines @ 85°C
- Integrated 30 Ω termination resistors
- Diode clamps to V_{CC} and GND on all inputs
- Input diodes to accommodate strong drivers

DESCRIPTION

The 74ALVC162836A is an 20-bit universal bus driver. Data flow is controlled by output enable (\overline{OE}), latch enable (\overline{LE}) and clock inputs (CP).

When $\Box E$ is HIGH, the A to Y data flow is transparent. When $\Box E$ is HIGH and CP is held at LOW or HIGH, the data is latched; on the LOW to HIGH transient of CP the A-data is stored in the latch/flip-flop.

The 74ALVC162836A is designed with 30 Ω_series resistors in both HIGH or LOW output stages.

When \overline{OE} is LOW the outputs are active. When \overline{OE} is HIGH, the outputs go to the high impedance OFF-state. Operation of the \overline{OE} input does not affect the state of the latch/flip -flop.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIO	TYPICAL	UNIT	
t _{PHL} /t _{PLH}	Propagation delay An to Yn; LE to Yn; CP to Yn	V_{CC} = 3.3 V, C _L = 50 pF		2.9 3.5 3.3	ns
f _{max}	Maximum clock frequency	$V_{CC} = 3.3 \text{ V}, C_{L} = 50 \text{ pF}$		240	MHz
Cl	Input capacitance			4.0	pF
C _{I/O}	Input/Output capacitance		_	8.0	pF
	Power dissipation capacitance per buffer	$V_1 = GND$ to V_{CC}^1	transparent mode Output enabled Output disabled	10 3	n F
C _{PD}	Power dissipation capacitance per builer		Clocked mode Output enabled Output disabled	21 15	pF

NOTES:

I. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where: } f_{i} = \text{input frequency in MHz; } C_{L} = \text{output load capacitance in pF;}$

 f_0 = output frequency in MHz; V_{CC} = supply voltage in V; Σ ($C_L \times V_{CC}^2 \times f_0$) = sum of outputs.

OE 56 CP 1 Y_1 2 55 A₁ 54 3 Y₂ A2 GND 4 53 GND 52 5 A₃ Y₃ 51 Y_4 6 A_4 V_{CC} 7 50 V_{CC} 49 Y_5 8 A_5 48 Y₆ 9 A_6 47 10 Y₇ A7 46 GND 11 GND 12 45 Y₈ A₈ 44 13 Ag Y9 43 14 A₁₀ Y₁₀ 42 Y₁₁ 15 A₁₁ 41 Y₁₂ 16 A₁₂ 40 17 Y₁₃ A₁₃ GND 39 GND 18 19 38 Y₁₄ A_{14} 37 20 Y₁₅ A₁₅ 21 36 Y₁₆ A₁₆ V_{CC} 35 V_{CC} 22 34 23 A₁₇ Y₁₇ 33 24 A₁₈ Y₁₈ 32 GND 25 GND 31 26 Y₁₉ A₁₉ 27 30 Y₂₀ A₂₀ NC 28 29 LE SH00197

PIN CONFIGURATION

74ALVC162836A

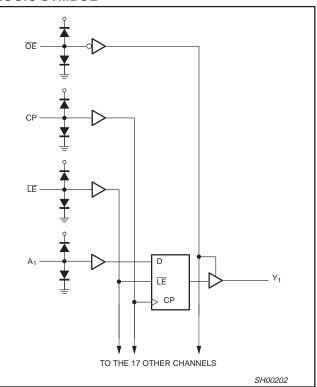
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
56-Pin Plastic Thin Shrink Small Outline (TSSOP) Type II	–40°C to +85°C	74ALVC162836A DGG	SOT364-1

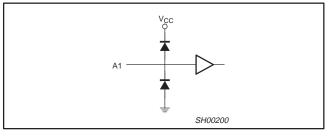
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
28	NC	No connection
2, 3, 5, 6, 8, 9, 10, 12, 13, 14, 15, 16, 17, 19, 20, 21, 23, 24, 26, 27	Y_1 to Y_{18}	Data outputs
4, 11, 18, 25, 32, 39, 46, 53, 56	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
1	ŌĒ	Output enable input (active LOW)
29	LE	Latch enable input (active LOW)
56	CP	Clock input
55, 54, 52, 51, 49, 48, 47, 45, 44, 43, 42, 41, 40, 38, 37, 36, 34, 33, 31, 30	A_1 to A_{18}	Data inputs

LOGIC SYMBOL

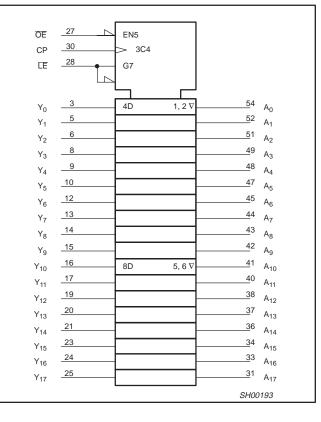


TYPICAL INPUT (DATA OR CONTROL)



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LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

	INPUTS					
OE	LE	СР	Α	Y		
Н	Х	Х	Х	Z		
L	L	Х	L	L		
L	L	Х	Н	Н		
L	Н	\uparrow	L	L		
L	Н	\uparrow	Н	Н		
L	Н	Н	Х	Y ₀ 1		
L	Н	L	Х	Y ₀ ²		

HIGH voltage level Н =

L = LOW voltage level

Don't care =

X Z ↑ = High impedance "off" state

LOW-to-HIGH level transition =

NOTES:

1. Output level before the indicated steady-state input conditions were established, provided that CP is high before $\overline{\text{LE}}$ goes low.

2. Output level before the indicated steady-state input conditions were established.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
	DC supply voltage 2.5 V range (for max. speed performance @ 30 pF output load)		2.3	2.7	
V _{CC}	DC supply voltage 3.3 V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
	DC supply voltage (for low-voltage applications)		1.2	3.6	
VI	DC Input voltage range		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	V _{CC} = 2.3 to 3.0 V V _{CC} = 3.0 to 3.6 V	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ <0	-50	mA
VI	DC input voltage	Note 1	-0.5 to +4.6	V
I _{OK}	DC output diode current	$V_O > V_{CC} \text{ or } V_O < 0$	± 50	mA
Vo	DC output voltage	Note 1	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	± 50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package –plastic medium-shrink (SSOP) –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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20-bit registered driver with inverted register enable and 30Ω termination resistors (3-State)

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp =	= -40°C to +8	5°C	
			MIN	IIN TYP ¹ MAX		1
		V _{CC} = 2.3 to 2.7 V	1.7	1.2		
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6 V	2.0	1.5		V V
		V _{CC} = 2.3 to 2.7 V		1.2	0.7	
VIL	LOW level Input voltage	V _{CC} = 2.7 to 3.6 V		1.5	0.8	
		$V_{CC} = 2.3 \text{ to } 3.6 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL};$ $I_{O} = -100 \ \mu\text{A}$	V _{CC} -0.2	V _{CC}		
		V_{CC} = 2.3 V; V_I = V_{IH} or V_{IL} ; I_O = -4 mA	V _{CC} -0.4	V _{CC} _0.11		1
		V_{CC} = 2.3 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -6 mA	V _{CC} -0.6	V _{CC} -0.17		1
V _{OH}	HIGH level output voltage	V_{CC} = 2.7 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -4 mA	V _{CC} -0.5	V _{CC} -0.09		
		V_{CC} = 2.7 V; V_I = V_{IH} or V_{IL} ; I_O = -8 mA	V _{CC} -0.7	V _{CC} -0.19		
		$V_{CC} = 3.0 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = -6 \text{ mA}$	V _{CC} -0.6	V _{CC} -0.13		1
		V_{CC} = 3.0 V; V_I = V_{IH} or V_{IL} ; I_O = -12 mA	V _{CC} -1.0	V _{CC} -0.27		1
		V_{CC} = 2.3 to 3.6 V; V_{I} = V_{IH} or $V_{IL};$ I_{O} = 100 μA		GND	0.20	
		V_{CC} = 2.3 V; V_I = V_{IH} or V_{IL} ; I_O = 4 mA		0.07	0.40	
		V_{CC} = 2.3 V; V_I = V_{IH} or V_{IL} ; I_O = 6 mA		0.11	0.55]
V _{OL}	LOW level output voltage	V_{CC} = 2.7 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 4 mA		0.06	0.40	
		V_{CC} = 2.7 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 8 mA		0.13	0.60	
		V_{CC} = 3.0 V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 6 mA		0.09	0.55	
		V_{CC} = 3.0 V; V_{I} = V_{IH} or $V_{IL;}$ I_{O} = 12 mA		0.19	0.80	
I _I	Input leakage current	$V_{CC} = 2.3 \text{ to } 3.6 \text{ V};$ $V_I = V_{CC} \text{ or GND}$		0.1	5	μ/
I _{OZ}	3-State output OFF-state current	$ \begin{array}{l} V_{CC} = 2.3 \text{ to } 3.6 \text{ V}; V_{I} = V_{IH} \text{ or } V_{IL}; \\ V_{O} = V_{CC} \text{ or } \text{GND} \end{array} $		0.1	10	μ/
I _{CC}	Quiescent supply current	V_{CC} = 2.3 to 3.6 V; V_{I} = V_{CC} or GND; I_{O} = 0		0.2	40	μA
ΔI_{CC}	Additional quiescent supply current	$V_{CC} = 2.3 \text{ V}$ to 3.6 V; $V_{I} = V_{CC} - 0.6 \text{ V}$; $I_{O} = 0$		150	750	μA

NOTE:

1. All typical values are at $T_{amb} = 25^{\circ}C$.

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AC CHARACTERISTICS FOR V_{CC} = 2.3 V TO 2.7 V RANGE

 $GND = 0 \text{ V}; t_r = t_f \leq 2.0 \text{ ns}; C_L = 30 \text{ pF}$

				LIMITS			
SYMBOL	PARAMETER	WAVEFORM	V	UNIT			
			MIN	TYP ¹	MAX	1	
	Propagation delay An to Yn	1, 7	1.0	3.5	4.4		
t _{PHL} /t _{PLH}	Propagation delay LE to Yn	2, 7	1.1	3.5	5.0	ns	
	Propagation delay CP to Yn	4, 7	1.0	3.7	5.4	7	
t _{PZH} /t _{PZL}	3-State output enable time OE to Yn	6, 7	1.1	3.5	5.0	ns	
t _{PHZ} /t _{PLZ}	3-State output disable time OE to Yn	6, 7	1.0	2.8	4.5 ns		
4	CP pulse width HIGH or LOW	4, 7	3.3	1.0	-		
t _W	LE pulse width HIGH	2,7	3.3	0.7	-	ns	
	Set-up time An to CP	5, 7	0.3	-0.2	-	1	
tsu	Set-up time An to LE	5, 7	0.5	0	-	ns	
	Hold time An to CP	3, 7	1.0	0.4	-	1	
t _h	Hold time An to LE	3, 7	0.5	0.1	-	ns	
f _{max}	Maximum clock pulse frequency	4, 7	150	190	-	MHz	

NOTE:

1. All typical values are at V_{CC} = 2.5 V and T_{amb} = 25°C.

AC CHARACTERISTICS FOR V_{CC} = 3.0 V TO 3.6 V RANGE AND V_{CC} = 2.7 V

GND = 0 V; $t_r = t_f \le 2.5 \text{ ns}$; $C_L = 50 \text{ pF}$

				LIMITS			LIMITS		
SYMBOL	PARAMETER	WAVEFORM	Vc	_C = 3.3 ± 0.3	3 V	,	V _{CC} = 2.7 V	,	
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	1
	Propagation delay An to Yn	1, 7	1.2	2.8	4.3	-	3.3	4.6	
t _{PHL} /t _{PLH}	Propagation delay LE to Yn	2, 7	1.4	2.8	4.4	-	3.4	4.8	ns
	Propagation delay CP to Yn	4, 7	1.1	3.2	4.9	-	3.8	5.2	1
t _{PZH} /t _{PZL}	3-State output enable time $\overline{\text{OE}}$ to Yn	6, 7	1.2	2.7	4.5	-	3.7	5.0	ns
t _{PHZ} /t _{PLZ}	3-State output disable time OE to Yn	6, 7	1.7	3.4	4.8	-	3.5	4.9	ns
	CP pulse width HIGH or LOW	4, 7	3.3	0.7	-	3.3	1.2	-	
t _W	LE pulse width HIGH	2, 7	3.3	0.6	-	3.3	0.6	-	ns
4	Set-up time An to CP	5, 7	0.3	-0.2	-	0.3	-0.2	-	ns
t _{SU}	Set-up time An to LE	5, 7	0.5	0	-	0.5	0	-	
	Hold time An to CP	3, 7	1.2	1.2	_	1.2	0.4	-	1
t _h	Hold time An to LE	3, 7	1.0	0.4	—	1.0	0.1	-	ns
f _{max}	Maximum clock pulse frequency	4, 7	150	240	-	150	190	-	MHz

NOTES:

1. All typical values are measured $T_{amb} = 25^{\circ}C$.

2. Typical value is measured at V_{CC} = 3.3 V.

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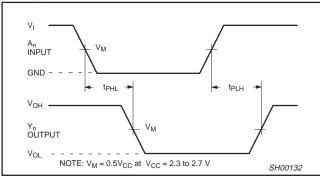
AC WAVEFORMS FOR V_{CC} = 3.0 V TO 3.6 V AND V_{CC} = 2.7 V RANGE

 V_M = 1.5 V V_X = V_{OL} + 0.3 V V_Y = V_{OH} – 0.3 V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. V_I = 2.7 V

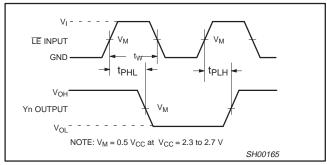
AC WAVEFORMS FOR V_{CC} = 2.3 V TO 2.7 V AND V_{CC} < 2.3 V RANGE

 $V_{M} = 0.5 V_{CC}$ $V_{X} = V_{OL} + 0.15 V$ $V_{Y} = V_{OH} - 0.15 V$ V_{OL} and V_{OH} are the typic

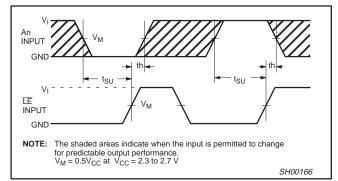
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. $V_{I} = V_{CC}$



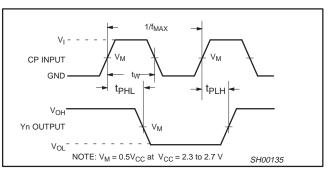
Waveform 1. Input (Dn) to output (Yn) propagation delay



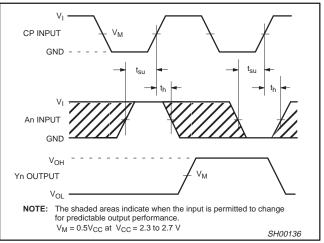
Waveform 2. Latch enable input (LE) pulse width, the latch enable input to output (Yn) propagation delays.



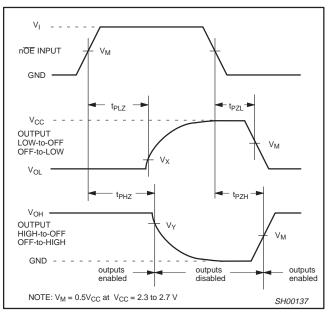
Waveform 3. Data set-up and hold times for the An input to the LE input



Waveform 4. The clock (CP) to Yn propagation delays, the clock pulse width and the maximum clock frequency.



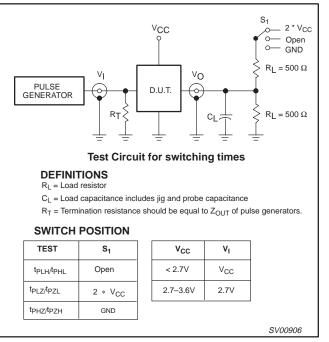
Waveform 5. Data set-up and hold times for the An input to the clock CP input



Waveform 6. 3-State enable and disable times

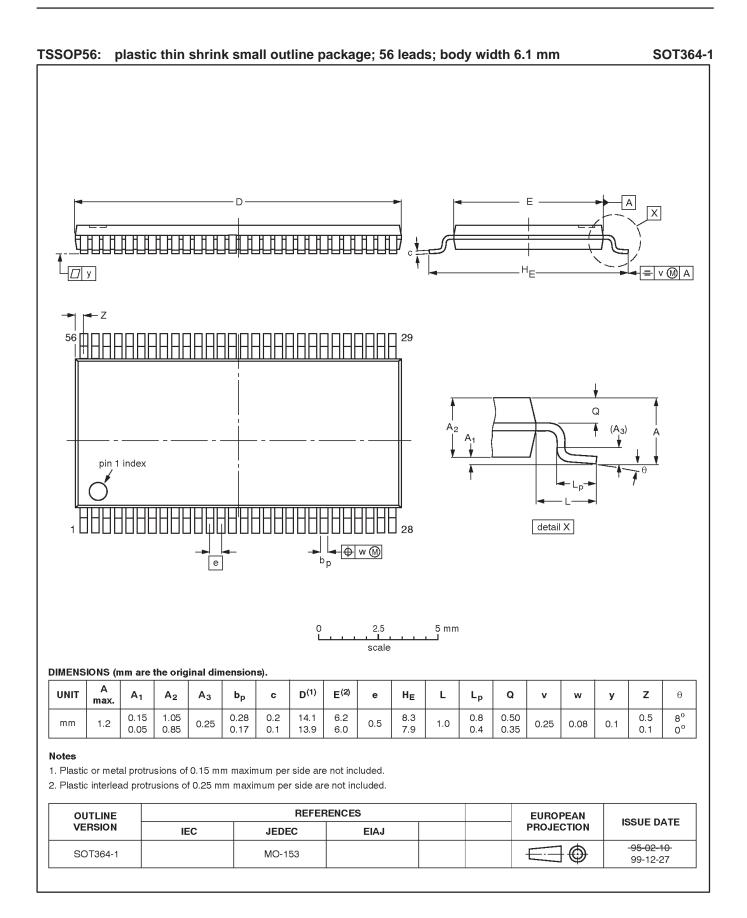
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TEST CIRCUIT



Waveform 7. Load circuitry for switching times

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NOTES

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Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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